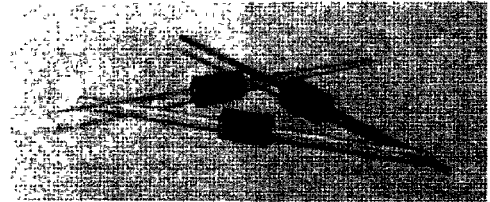
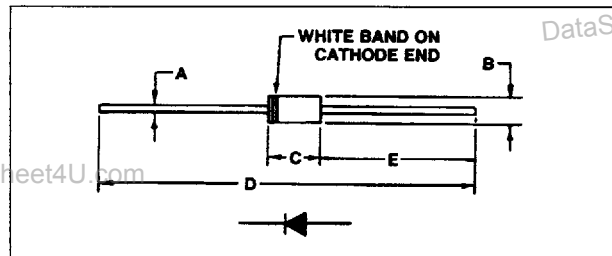


3 Amp Schottky Rectifiers 150°C MAX T_J

20 Volt, 30 Volt and 40 Volt V_{RRM}
 .475 Volt V_F at I_F = 3.0 Amps
 Very Fast Switching Speed
 Minimum Sized, Low Cost Epoxy Encapsulation



LTR.	INCHES	MILLIMETERS
A	.048-.052 Dia.	1,22-1,32 Dia.
B	.190-.225	4,83-5,72
C	.36-.37	9,14-9,40
D	2,6-2,8	66,0-71,1
E	1.137-1.237	28,33-31,42



MAXIMUM RATINGS (At T_A = 25°C unless otherwise noted)

RATINGS	SYMBOL	VSK320	VSK330	VSK340	UNITS
DC Blocking Voltage	V _{RRM}				
Working Peak Reverse Voltage	V _{RRM}	20	30	40	Volts
Peak Repetitive Reverse Voltage	V _{RRM}				
RMS Reverse Voltage	V _{R(RMS)}}	14	21	28	Volts
Average Rectified Forward Current (Fig. 5 & 6)	I _O	3.0			Amps
Ambient Temp. @ Rated V _{RRM} , P _{RAJA} ≤ 24°C/W	T _A	85	80	75	°C
Peak Surge Current (non-rep), 300μs Pulse Width (Fig. 4)	I _{FSM}	250			Amps
Peak Surge Current (non-rep), 1/2 cycle, 60Hz (Fig. 4)	I _{FSM}	150			Amps
Operating Junction Temperature	T _J	-65 to +150*			°C
Storage Temperature	T _{STG}	-65 to +150			°C

* V_{RRM} ≤ 0.1 V_{RRM} Max, P_{RAJA} ≤ 32°C/W

ELECTRICAL CHARACTERISTICS (At T_A = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	VSK320	VSK330	VSK340	UNITS
Maximum Instantaneous Forward Voltage Drop (1) See Fig. 2 for Typical V _F	V _F		.400 .475 .750		Volts
Maximum Instantaneous Reverse Current at Rated V _{RRM} (1) See Fig. 1 for Typical I _R	I _R		3.0 30.0		mA

(1) Pulse Test: Pulse Width = 300 μs, Duty Cycle = 2%

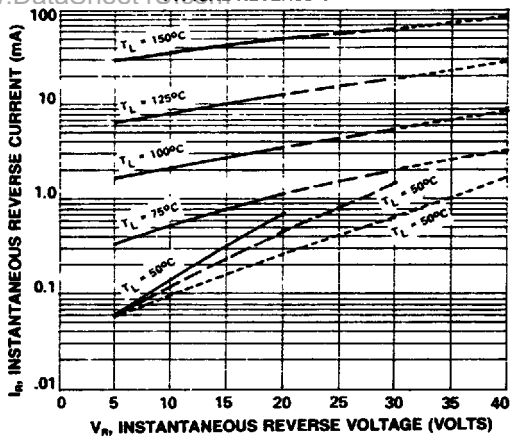


FIGURE 1

— VSK320
 - - - VSK330
 - - - VSK340
 PULSE WIDTH - 300 μ sec
 T_L = LEAD TEMP. MEASURED
 .03" FROM
 RECTIFIER BODY WITH
 40 GAUGE THERMOCOUPLE

T-03-1

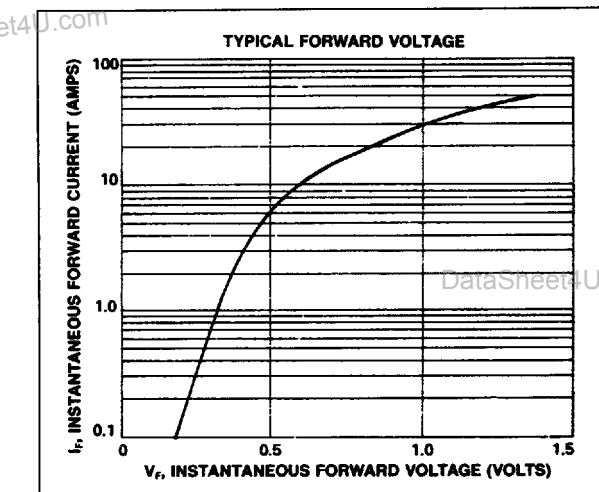


FIGURE 2

PULSE WIDTH = 300 μ sec
 T_A = 25°C

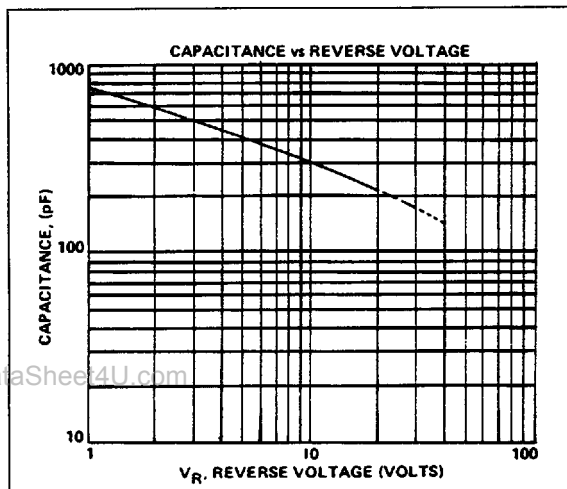


FIGURE 3

— VSK320
 - - - VSK330
 - - - VSK340
 T_A = 25°C
 TEST FREQ. = 100 kHz

The current flow in Schottky barrier rectifier is due to majority carrier conduction and is not affected by reverse recovery transients due to stored charge and minority carrier injection as in conventional PN diodes.

The Schottky barrier rectifier may be considered for purposes of circuit analysis, as an ideal diode in parallel with a variable capacitance equal in value to the junction capacitance. See Figure 3.

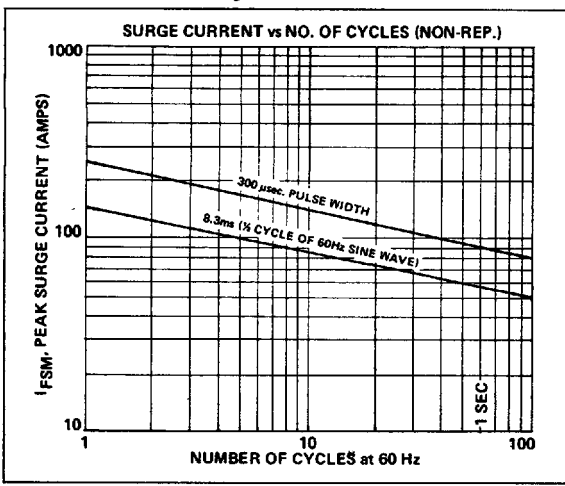


FIGURE 4

$T_A = 25^\circ\text{C}$

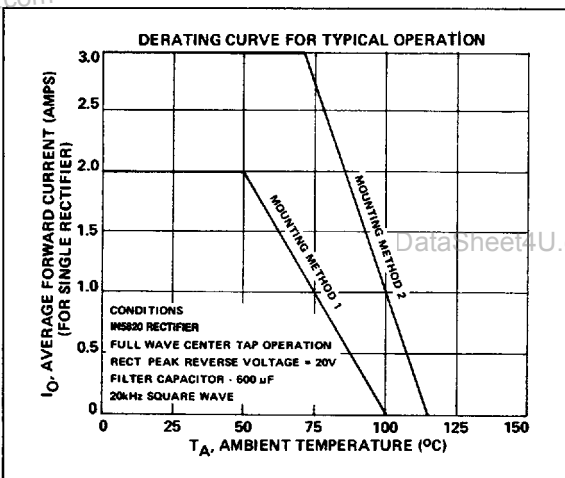
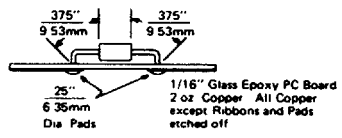


FIGURE 5

MOUNTING METHOD 1



MOUNTING METHOD 2 - TOP VIEW

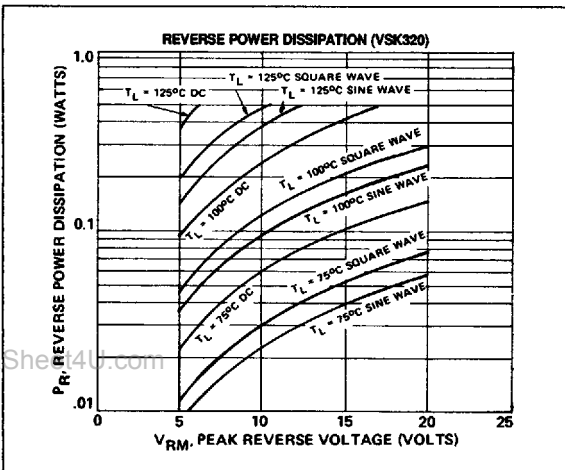
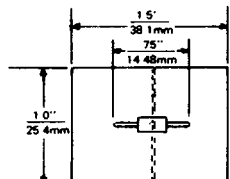
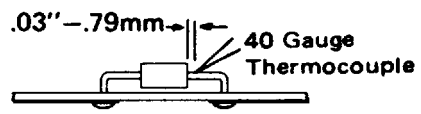


FIGURE 6(A)



REVERSE POWER MULTIPLIES 1.32x FOR EACH 5°C TEMP. INCREASE.

USE THIS MULTIPLIER FOR INTERPOLATION BETWEEN CURVES SHOWN ON FIGURES 6(A), 6(B), 6(C).

USE 75°C CURVES FOR ALL TEMPS. BELOW 75°C

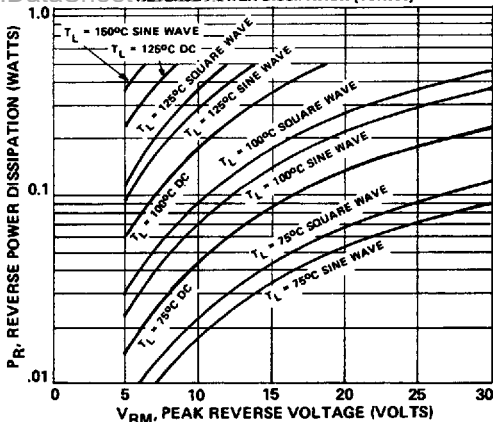


FIGURE 6(B)

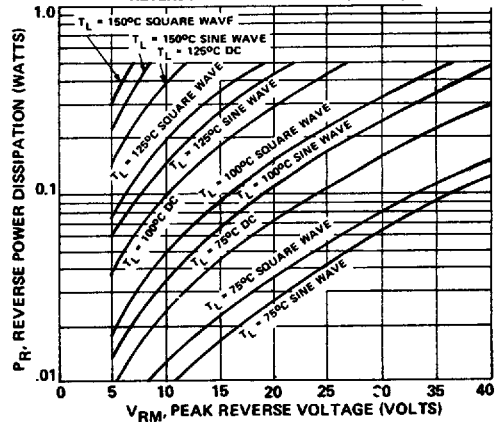


FIGURE 6(C)

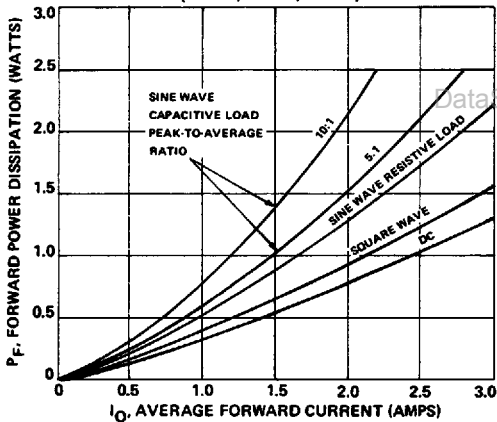
FORWARD POWER DISSIPATION
(VSK320, VSK330, VSK340)

FIGURE 6(D)

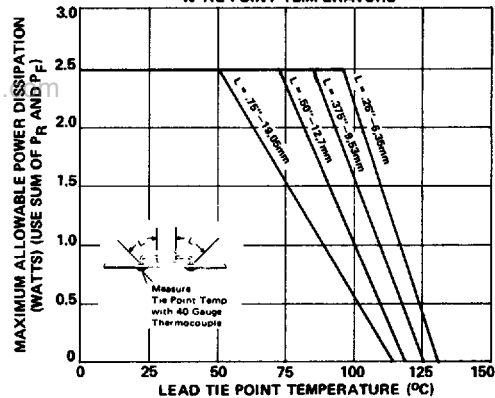
MAXIMUM ALLOWABLE POWER DISSIPATION
vs TIE POINT TEMPERATURE

FIGURE 6(E)

Thermal Considerations:

- The derating curve of figure 5 may be used for initial design work.
- Use the curves of figure 6 to study the voltage / current / temperature parameters. These curves are helpful in determining the rectifier capability when connected to a tie point whose temperature is influenced by other heat producing components. To use these curves, add the reverse power dissipation from figure 6 (A), (B) or (C) to the forward power dissipation from figure 6 (D). Then go to figure 6 (E) to find the maximum allowable tie point temperature.
- The heat sink (tie point) must be designed to keep the temperature at this point below that shown on the figure 6 (E) curve. Thermal runaway is entirely possible on marginal designs due to the inherently large reverse leakage of Schottky barrier rectifiers and the fact that reverse power multiplies about 1.32 times for each 5°C of temperature increase.

- The curves of figure 6 (E) were based on full rated reverse bias voltage. Slightly higher tie point temperatures can be tolerated at lower voltages. We recommend that all designs be verified at an ambient temperature at least 10°C higher than the maximum at which the equipment will ever have to operate.
- If the application is such that DC reverse bias is applied nearly 100% of the time, all temperature points on curve 6 (E) should be reduced 13°C.
- These thermal resistances apply: $R_{th(j-c)}$ (measured $1/32"$ from epoxy) = 6°C/W and the lead = 25°C/W per inch when equal heatsinking is applied to each lead.